



Is Now Part of



**ON Semiconductor®**

To learn more about ON Semiconductor, please visit our website at  
[www.onsemi.com](http://www.onsemi.com)

ON Semiconductor and the ON Semiconductor logo are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at [www.onsemi.com/site/pdf/Patent-Marking.pdf](http://www.onsemi.com/site/pdf/Patent-Marking.pdf). ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the design or manufacture of the part. ON Semiconductor is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

# 2SC5242/FJA4313

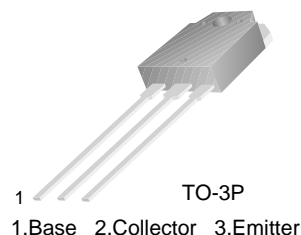
## NPN Epitaxial Silicon Transistor

### Applications

- High-Fidelity Audio Output Amplifier
- General Purpose Power Amplifier

### Features

- High Current Capability:  $I_C = 17A$
- High Power Dissipation : 130watts
- High Frequency : 30MHz.
- High Voltage :  $V_{CEO}=250V$
- Wide S.O.A for reliable operation.
- Excellent Gain Linearity for low THD.
- Complement to 2SA1962/FJA4213.
- Thermal and electrical Spice models are available
- Same transistor is also available in:
  - TO264 package, 2SC5200/FJL4315 : 150 watts
  - TO220 package, FJP5200 : 80 watts
  - TO220F package, FJPF5200 : 50 watts



### Absolute Maximum Ratings\* $T_a = 25^\circ C$ unless otherwise noted

Symbol	Parameter	Ratings	Units
$BV_{CBO}$	Collector-Base Voltage	250	V
$BV_{CEO}$	Collector-Emitter Voltage	250	V
$BV_{EBO}$	Emitter-Base Voltage	5	V
$I_C$	Collector Current(DC)	17	A
$I_B$	Base Current	1.5	A
$P_D$	Total Device Dissipation( $T_C=25^\circ C$ ) Derate above $25^\circ C$	130 1.04	W W/ $^\circ C$
$T_J, T_{STG}$	Junction and Storage Temperature	- 50 ~ +150	$^\circ C$

\* These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

### Thermal Characteristics\* $T_a=25^\circ C$ unless otherwise noted

Symbol	Parameter	Max.	Units
$R_{\theta JC}$	Thermal Resistance, Junction to Case	0.96	$^\circ C/W$

\* Device mounted on minimum pad size

### $h_{FE}$ Classification

Classification	R	O
$h_{FE1}$	55 ~ 110	80 ~ 160

**Electrical Characteristics\***  $T_a=25^\circ\text{C}$  unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
$BV_{CBO}$	Collector-Base Breakdown Voltage	$I_C=5\text{mA}, I_E=0$	250			V
$BV_{CEO}$	Collector-Emitter Breakdown Voltage	$I_C=10\text{mA}, R_{BE}=\infty$	250			V
$BV_{EBO}$	Emitter-Base Breakdown Voltage	$I_E=5\text{mA}, I_C=0$	5			V
$I_{CBO}$	Collector Cut-off Current	$V_{CB}=230\text{V}, I_E=0$			5.0	$\mu\text{A}$
$I_{EBO}$	Emitter Cut-off Current	$V_{EB}=5\text{V}, I_C=0$			5.0	$\mu\text{A}$
$h_{FE1}$	DC Current Gain	$V_{CE}=5\text{V}, I_C=1\text{A}$	55		160	
$h_{FE2}$	DC Current Gain	$V_{CE}=5\text{V}, I_C=7\text{A}$	35	60		
$V_{CE}(\text{sat})$	Collector-Emitter Saturation Voltage	$I_C=8\text{A}, I_B=0.8\text{A}$		0.4	3.0	V
$V_{BE}(\text{on})$	Base-Emitter On Voltage	$V_{CE}=5\text{V}, I_C=7\text{A}$		1.0	1.5	V
$f_T$	Current Gain Bandwidth Product	$V_{CE}=5\text{V}, I_C=1\text{A}$		30		MHz
$C_{ob}$	Output Capacitance	$V_{CB}=10\text{V}, f=1\text{MHz}$		200		pF

\* Pulse Test: Pulse Width=20 $\mu\text{s}$ , Duty Cycle $\leq$ 2%**Ordering Information**

Part Number	Marking	Package	Packing Method	Remarks
2SC5242RTU	C5242R	TO-3P	TUBE	hFE1 R grade
2SC5242OTU	C5242O	TO-3P	TUBE	hFE1 O grade
FJA4313RTU	J4313R	TO-3P	TUBE	hFE1 R grade
FJA4313OTU	J4313O	TO-3P	TUBE	hFE1 O grade

# Typical Characteristics

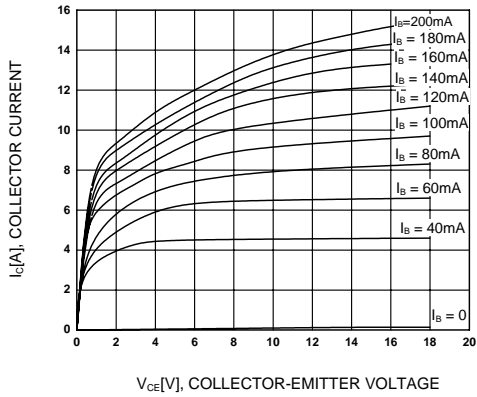


Figure 1. Static Characteristic

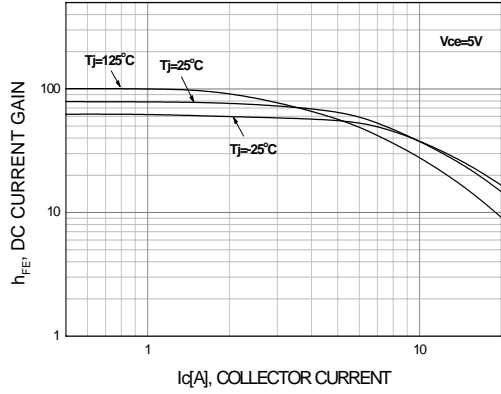


Figure 2. DC current Gain ( R grade )

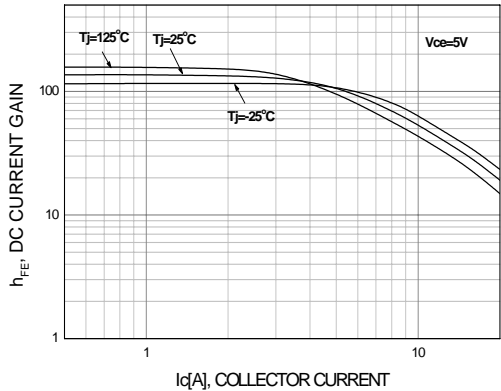


Figure 3. DC current Gain ( O grade )

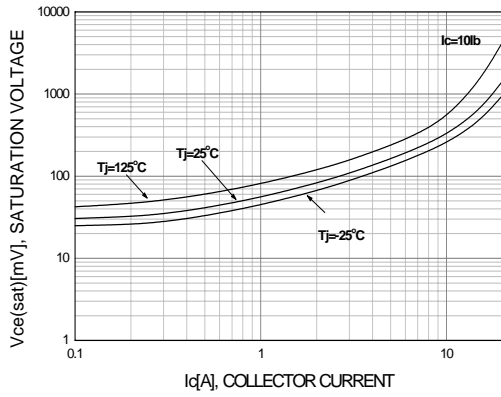


Figure 4. Collector-Emitter Saturation Voltage

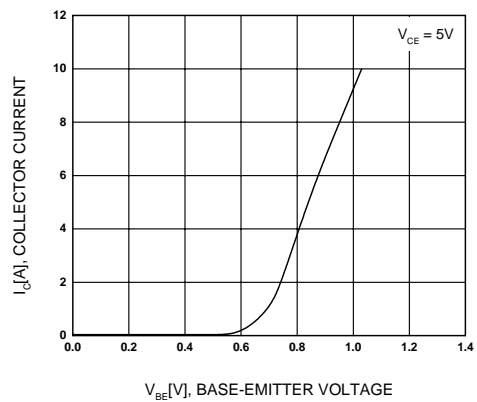


Figure 5. Base-Emitter On Voltage

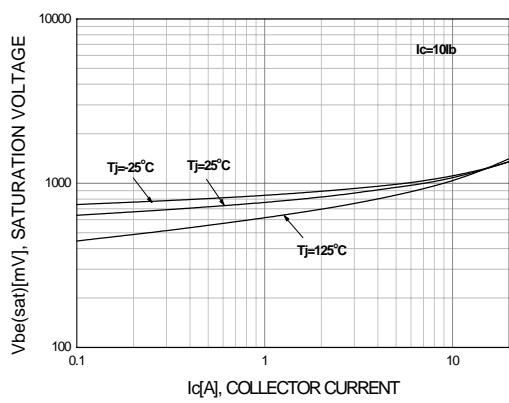


Figure 6. Base-Emitter Saturation Voltage

# Typical Characteristics

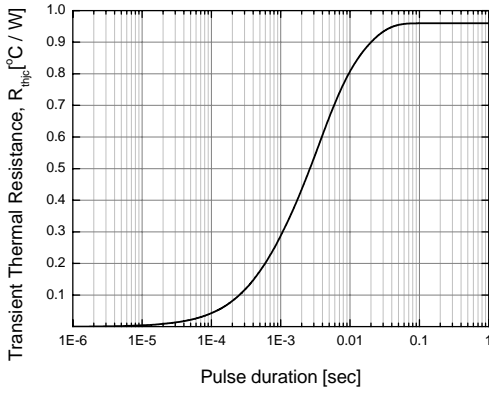


Figure 7. Thermal Resistance

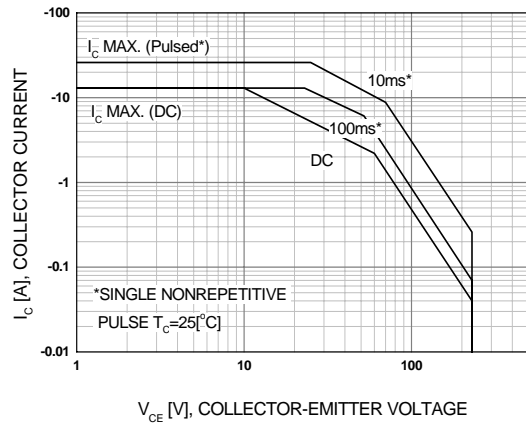


Figure 8. Safe Operating Area

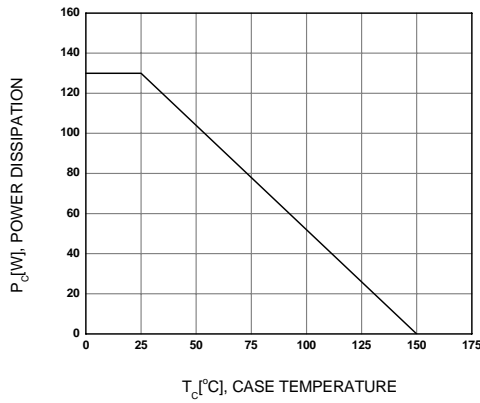
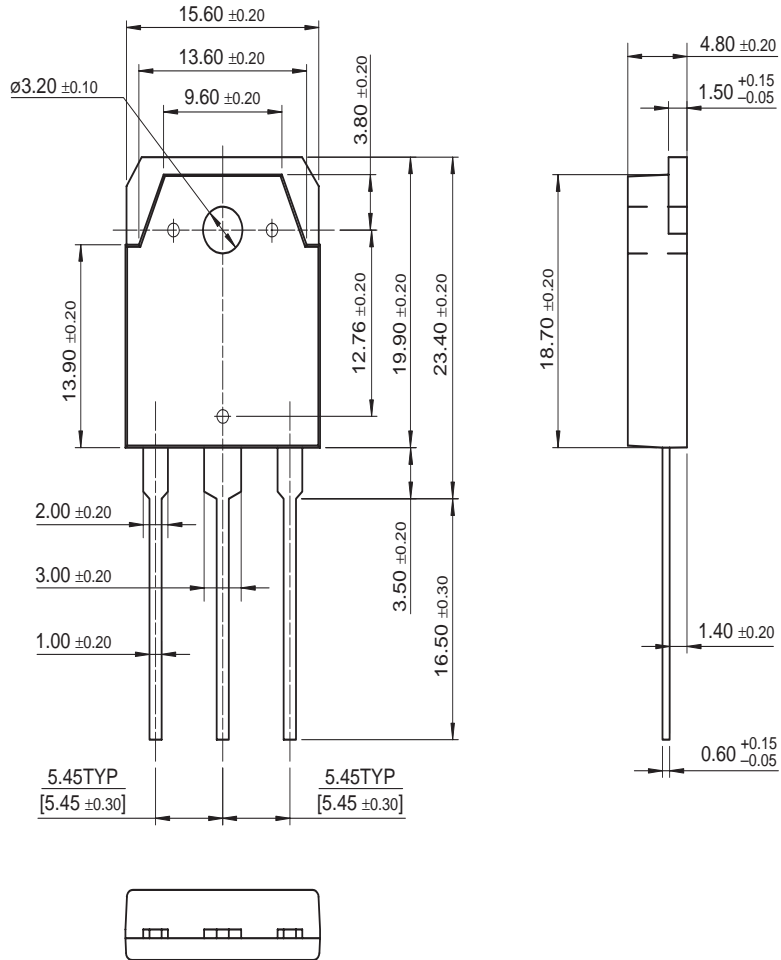


Figure 9. Power Derating

# Package Dimensions

## TO-3P



Dimensions in Millimeters



**TRADEMARKS**

The following includes registered and unregistered trademarks and service marks, owned by Fairchild Semiconductor and/or its global subsidiaries, and is not intended to be an exhaustive list of all such trademarks.

- |   |                        |   |   |
|---|------------------------|---|---|
| Build it Now™   | FPST™                  | PDP SPM™  | The Power Franchise®  |
| CorePLUSTM  | F-PFST™                | Power-SPM™  |  |
| CorePOWER™  | FRFET®                 | PowerTrench®  | TinyBoost™  |
| CROSSVOLT™  | Global Power Resource™ | Programmable Active Droop™  | TinyBuck™   |
| CTL™  | Green FPST™            | QFET®   | TinyLogic®  |
| Current Transfer Logic™   | Green FPS™ e-Series™   | QST™  | TINYOPTO™   |
| EcoSPARK®   | GTO™                   | Quiet Series™   | TinyPower™  |
| EfficientMax™   | IntelliMAX™            | RapidConfigure™   | TinyPVM™  |
| EZSWITCH™ *   | ISOPLANAR™             | Saving our world, 1mW at a time™  | TinyWire™   |
|  | MegaBuck™              | SmartMax™   | μSerDes™  |
|  | MICROCOUPLER™          | SMART START™  |  |
| Fairchild®  | MicroFET™              | SPM®  | UHC®  |
| Fairchild Semiconductor®  | MicroPak™              | STEALTH™  | Ultra FRFET™  |
| FACT Quiet Series™  | MillerDrive™           | SuperFET™   | UniFET™   |
| FACT®   | MotionMax™             | SuperSOT™.3   | VCX™  |
| FAST®   | Motion-SPM™            | SuperSOT™.8   | VisualMax™  |
| FastvCore™  | OPTOLOGIC®             | SupreMOS™   |   |
| FlashWriter®  | OPTOPLANAR®            | SyncFET™  |   |
|   |                        |  |   |

\* EZSWITCH™ and FlashWriter® are trademarks of System General Corporation, used under license by Fairchild Semiconductor.

**DISCLAIMER**

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

**LIFE SUPPORT POLICY**

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

As used herein:

- Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.
- A critical component in any component of a life support, device, or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

**ANTI-COUNTERFEITING POLICY**

Fairchild Semiconductor Corporation's Anti-Counterfeiting Policy. Fairchild's Anti-Counterfeiting Policy is also stated on our external website, [www.fairchildsemi.com](http://www.fairchildsemi.com), under Sales Support.

Counterfeiting of semiconductor parts is a growing problem in the industry. All manufacturers of semiconductor products are experiencing counterfeiting of their parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed applications, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handling and storage and provide access to Fairchild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address any warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. Fairchild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.

**PRODUCT STATUS DEFINITIONS**

**Definition of Terms**

Datasheet Identification	Product Status	Definition
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.

Rev. I35

# Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

[Fairchild Semiconductor:](#)

[FJA4313RTU](#) [FJA4313OTU](#)